

Photocouplers Photorelay

TLP220A

1. Applications

- · Mechanical relay replacements
- · Security Systems
- Measuring Instruments
- · Factory Automation (FA)
- · Amusement Equipment
- · Smart Meters
- · Electricity Meters

2. General

The TLP220A photorelay consists of a photo MOSFET optically coupled to an infrared light emitting diode. It is housed in a 4-pin DIP package. It provides an isolation voltage of 5000 Vrms, making it suitable for applications that require reinforced insulation.

3. Features

- (1) Normally open (1-Form-A)
- (2) OFF-state output terminal voltage: 60 V (min)
- (3) Trigger LED current: 2 mA (max)
- (4) ON-state current: 500 mA (max)
- (5) ON-state resistance: 2Ω (max)
- (6) Isolation voltage: 5000 Vrms (min)
- (7) Safety standards

UL-approved: UL1577, File No.E67349

cUL-approved: CSA Component Acceptance Service No.5A File No.E67349

VDE-approved: EN60747-5-5 (Note 1)

CQC-approved: GB4943.1, GB8898 Japan Factory

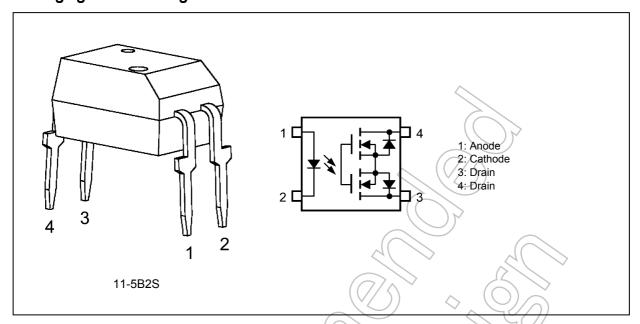
Note 1: When an EN60747-5-5 approved type is needed, please designate the Option (D4).

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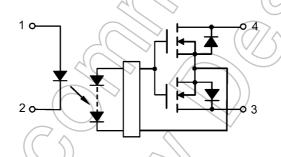




4. Packaging and Pin Assignment



5. Internal Circuit



6. Mechanical Parameters

Characteristics	7.62-mm Pitch TLP220A	10.16-mm Pitch TLP220AF	Unit
Creepage distances	7.0 (min)	8.0 (min)	mm
Clearance distances	7.0 (min)	8.0 (min)	
Internal isolation thickness	0.4 (min)	0.4 (min)	

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7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

	Characteris	tics	Symbol	Note	Rating	Unit
LED	Input forward current		I _F		30	mA
	Input forward current derating	(T _a ≥ 25 °C)	$\Delta I_F/\Delta T_a$		-0.3	mA/°C
	Input forward current (pulsed)	(100 μs pulse, 100 pps)	I _{FP}	\wedge	1	Α
	Input reverse voltage		V_R		5	V
	Input power dissipation		P_{D}		50	mW
	Input power dissipation derating	(T _a ≥ 25 °C)	$\Delta P_D/\Delta T_a$		-0.5	mW/°C
	Junction temperature		T _j	77^	125	°C
Detector	OFF-state output terminal voltage		VOFF		60	V
	ON-state current		ION		500	mA
	ON-state current derating	$(T_a \ge 25 ^{\circ}C)$	ΔΙ _{ΟΝ} /ΔΤ _a	P	-5	mA/°C
	ON-state current (pulsed)	(t = 100 ms, duty = 1/10)	I _{ONP}		1.5	Α
	Output power dissipation	Y	Po		500	mW
	Output power dissipation derating	(T _a ≥ 25 °C)	$\Delta P_{O}/\Delta T_{a}$		-5.0	mW/°C
	Junction temperature		Tj	((125	°C
Common	Storage temperature		T _{stg}	7 /	-55 to 125	°C
	Operating temperature		T_{opr}		-40 to 85	°C
	Lead soldering temperature	(10 s)	T _{sol}		260	°C
	Isolation voltage	(AC, 60 s, R.H. ≤ 60 %)	BV _S	(Note 1)	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

8. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Supply voltage	V_{DD}				48	V
Input forward current	I _F		3	5	15	mA
ON-state current	I _{ON}				500	
Operating temperature	T _{opr}		-20	_	65	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this datasheet should also be considered.

9. Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

	Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
LED	Input forward voltage	V _F		I _F = 10 mA	1.45	1.63	1.75	V
	Input reverse current	I _R		V _R = 5 V			10	μА
	Input capacitance	Ct		V = 0 V, f = 1 MHz	_	40		pF
Detector	OFF-state current	I _{OFF}		V _{OFF} = 60 V	_	_	1	μА
	Output capacitance	C _{OFF}		V = 0 V, f = 1 MHz	_	130		pF



10. Coupled Electrical Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}		I _{ON} = 500 mA	_	0.3	2	mA
Return LED current	I _{FC}		I _{OFF} = 10 μA	0.1			mA
ON-state resistance	R _{ON}	(Note 1)	I _{ON} = 500 mA, I _F = 5 mA, Continuous	_	0.6	2	Ω

Note 1: Thermally saturated state.

11. Isolation Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz		0.8		pF
Isolation resistance	R _S	(Note 1)	V _S = 500 V, R.H. ≤ 60 %	1 × 10 ¹²	1014		Ω
Isolation voltage	BVS	(Note 1)	AC, 60 s	5000	_		Vrms
			AC, 1 s in oil	_	10000		
			DC, 60 s in oil	_	10000	\nearrow	Vdc

Note 1: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

12. Switching Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур	Max	Unit
Turn-on time	t _{ON}		See Fig. 12.1.	\sim	0.5	1	ms
Turn-off time	t _{OFF}	($R_L = 200 \Omega, V_{DD} = 20 V, I_F = 5 \text{mA}$)) —	0.2	1	

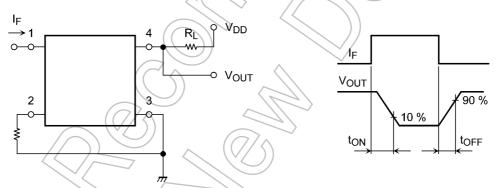
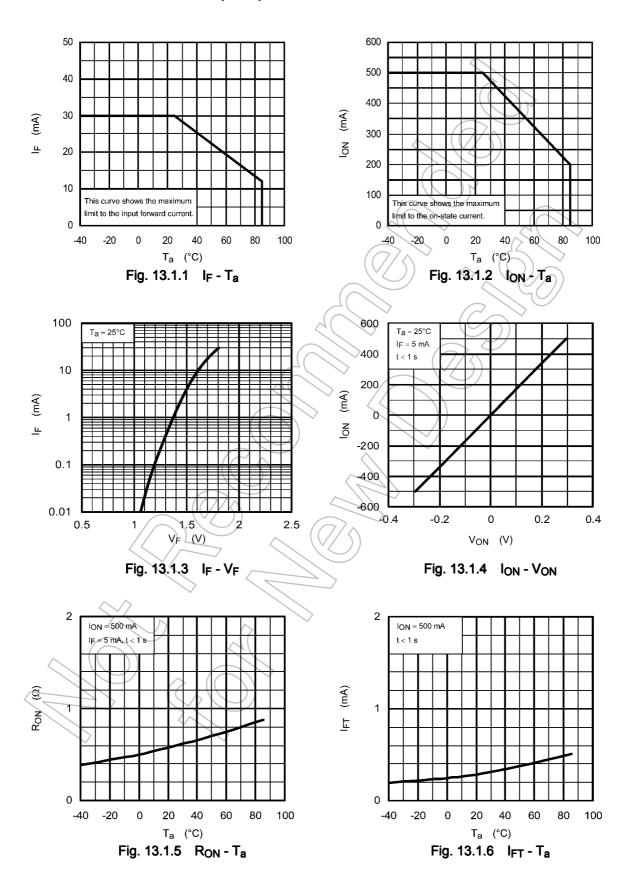


Fig. 12.1 Switching Time Test Circuit and Waveform

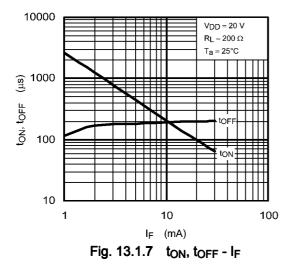


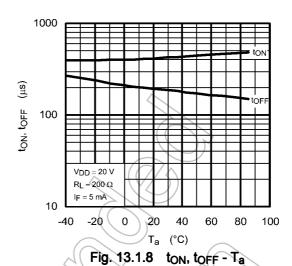
13. Characteristics Curves

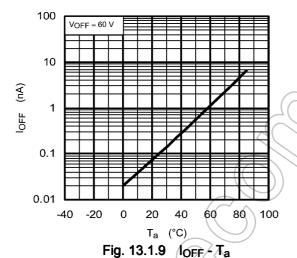
13.1. Characteristics Curves (Note)

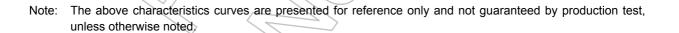










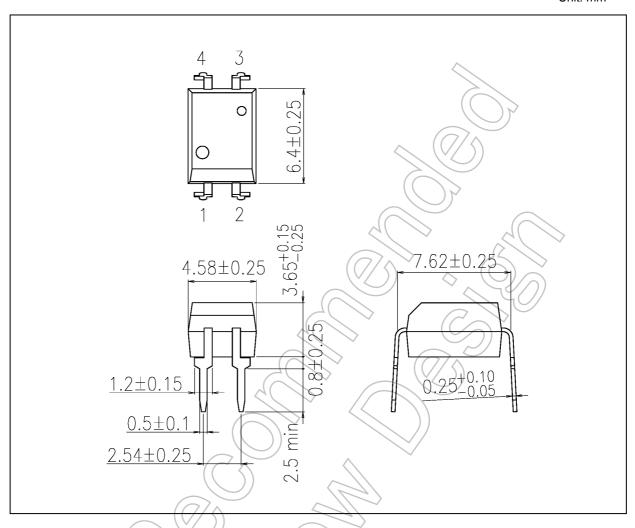


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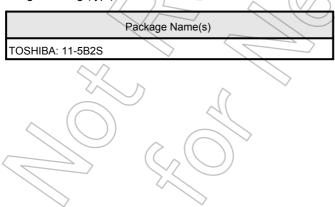


Package Dimensions

Unit: mm



Weight: 0.26 g (typ.)





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